NPN Epitaxial Planar Silicon Transistors



2SC4521

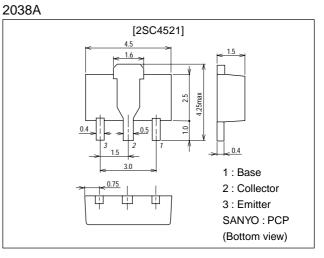
# **High-Speed Switching Applications**

### **Features**

- · Adoption of FBET, MBIT process.
- · Large current capacity.
- · Low collector-to-emitter saturation voltage.
- · Fast switching speed.
- · Small-sized package.

### Package Dimensions

unit:mm



## **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		60	V
Collector-to-Emitter Voltage	VCEO		45	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	ι <sub>C</sub>		3	A
Collector Current (Pulse)	ICP		6	A
Collector Dissipation	PC	Mounted on ceramic board (250mm <sup>2</sup> ×0.8mm)	1.5	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### **Electrical Characteristics at Ta = 25°C**

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	V <sub>CB</sub> =45V, I <sub>E</sub> =0			1	μA
Emitter Cutoff Current	IEBO	$V_{EB}=2V, I_{C}=0$			10	μA
DC Current Gain	h <sub>FE</sub> 1	$V_{CE}=2V, I_{C}=500mA$	100*		400*	
	h <sub>FE</sub> 2	V <sub>CE</sub> =2V, I <sub>C</sub> =3A	40			
Gain-Bandwidth Product	fT	$V_{CE}=2V, I_{C}=500mA$		300		MHz
Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz		25		pF

\* : The 2SC4521 is classified by 500mA  $h_{FE}$  as follows : 100 R 200 140 S 280 200 T 400

Marking : CL

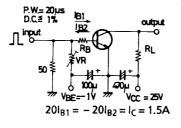
h<sub>FE</sub> rank : R, S, T

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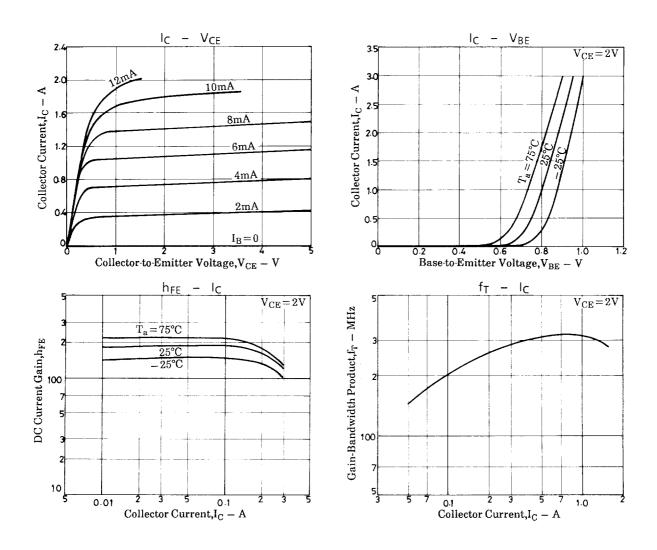
SANYO Electric Co., Ltd. Semiconductor Bussiness Headquaters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

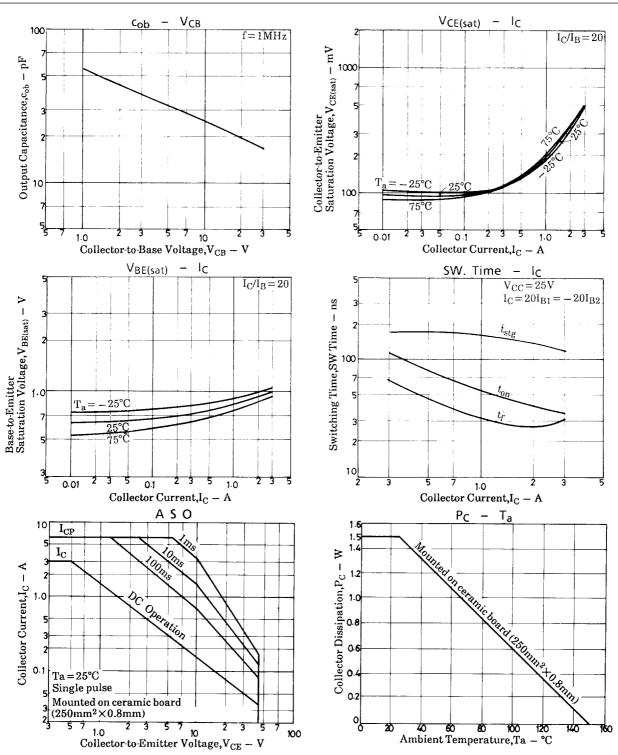
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =1.5A, I <sub>B</sub> =75mA		0.25	0.7	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =1.5V, I <sub>B</sub> =75mA		0.95	1.3	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =10µA, I <sub>E</sub> =0	60			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =1mA, R <sub>BE</sub> =∞	45			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =100μA, I <sub>C</sub> =0	5			V
Turn-ON Time	ton	See specified test circuit.		50	100	ns
Storage Time	tstg	See specified test circuit.		150	270	ns
Fall Time	t <sub>f</sub>	See specified test circuit.		180	350	ns

### **Switching Time Test Circuit**



Unit (resistance :  $\Omega$ , capacitance : F)





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